

ST2051

Enhanced power switch

Not recommended for new design

Features

- 90 mΩ high-side MOSFET switch
- 500 mA continuous current per channel
- Thermal and short-circuit protection with overcurrent logic output
- Operating range from 2.7 to 5.5 V
- CMOS- and TTL-compatible enable inputs
- 2.5 ms typical rise time
- Undervoltage lock out
- 10 μA maximum standby supply current
- Ambient temperature range, 0 °C to 85 °C
- 2 kV ESD protection
- Fault-blanking

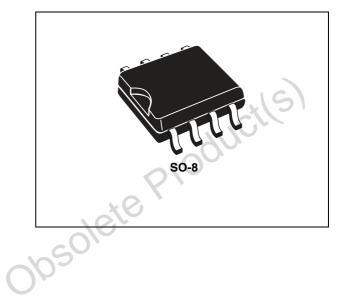


Table 1.Device summary

Order code	Package	Packaging
ST2051BDR ⁽¹⁾	SO-8	Tape and reel

1. Not recommended for new design (refer to STMPS2151MTR). Contact ST sales office for availability.

1 Description

The ST2051 power distribution switch is intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. These devices incorporate 90 m Ω N-channel MOSFET high-side power switches for power-distribution. The switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent logic output low. When continuous heavy overloads and short-circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures the switch remains off until valid input voltage is present.





Schematic diagram and pin connections 2

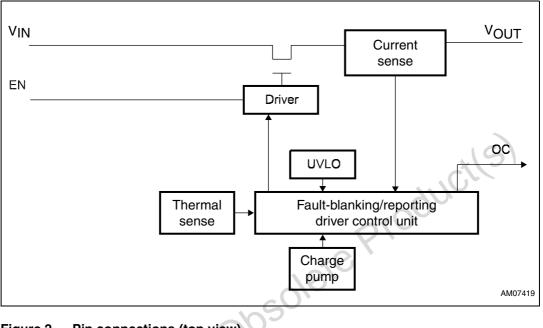
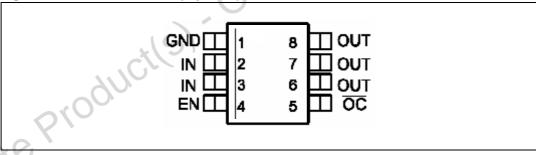


Figure 1. Schematic diagram

Figure 2. Pin connections (top view)



Pin functions

26	Table 2.	Pin functio	ons	
-vsu.	Pin	Name	Туре	Description
$\mathbf{O}\mathbf{V}$	1	GND	-	Ground
	2	IN1	-	V _{CC} input, 2.7-5.5 V
	3	IN2	-	V _{CC} input, 2.7-5.5 V
	4	EN	I	Enable (active hi)
	5	OC	0	Open drain output for fault indication
	6	OUT3	-	Output
	7	OUT2	-	Output
	8	OUT1	-	Output



3 Functional descriptions

3.1 Fault-blanking

ST devices feature a 10 ms fault-blanking. Fault-blanking allows current-limit faults, including momentary short-circuit faults that occur when hot-swapping a capacitive load, and also ensures that no fault is issued during power-up. When a load transient causes the device to enter current limit, an internal counter starts. If the load fault persists beyond the 10 ms fault-blanking timeout, the FAULT output asserts low. Load-transient faults less than 10 ms (typical) will not cause a FAULT output assertion. Only current-limit faults are blanked. Die overtemperature faults and input voltage drops below the undervoltage lock out (UVLO) threshold will cause an immediate fault output.

3.2 Overcurrent/overtemperature protection

In overcurrent or short-circuit condition, the switch limits the current at 500 mA. If temperature of die goes above limit value, the switch turns OFF.

3.3 Undervoltage lock out (UVLO)

When input voltage drops below critical value, the power switch turns OFF to prevent improper operation due to low voltage.

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4 Maximum rating

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only, and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics[™] SURE program and other relevant quality documents.

Symbol	Parameter	Value	Unit
VI	Input voltage range	-0.3-6.0	V
Vo	Output voltage range	-0.3-(V _I +0.3)	V
V _{IENX}	EN Input voltage range	-0.3-6.0	V
۱ ₀	Continuous output current	Internally limited	
ESD	ESD protection level	2	kV
TJ	Junction operating temperature	-40 to 125	°C
T _{STG}	Storage temperature	-55 to 150	°C

Table 3. Absolute maximum ratings

Table 4. Recommended operating conditions

	Symbol	Parameter	Min	Тур	Max	Unit
	VI	Input voltage	2.7	5.0	5.5	V
	V _O	Output voltage	0	5.0	5.5	V
	۱ ₀	Continuous output current	0	-	500	mA
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5 Electrical characteristics

Symbol	Parameter	Test conditions	Min	Тур	Мах	Unit
		V _I = 3.3 V; -40 < T _J < 125 °C		100	145	
R	Static drain-source	V _I = 5.0 V; -40 < T _J < 125 °C		90	135	mΩ
R _{DS(on)}	on-state resistance	V _I = 3.3 V; T _J = 25 °C		90	130	11152
		$V_I = 5.0 V;$ $T_J = 25 °C$		80	110	21
tr	Output rise time ⁽¹⁾	V _I = 5.5 V, R _L = 10 Ω, C _L = 1 μF	0	2.5		ms
۲		$V_{I} = 2.7 V,$ $R_{L} = 10 \Omega,$ $C_{L} = 1 \mu F$	¢	3		ms
	Output fall time ⁽¹⁾	V _I = 5.5 V, R _L = 10 Ω, C _L = 1 μF		0.3		ms
t _f	C	V _I = 2.7 V, R _L = 10 Ω, C _L = 1 μF		0.2		ms
T _{ON}	Turn-ON time ⁽¹⁾	R _L = 10 Ω C _L = 100 μF			20	ms
TOFF	Turn-OFF time ⁽¹⁾	$R_L = 10 $ Ω $C_L = 100 $ μF			40	ms

Table 5. Electrical characteristics ($T_J = 25 \text{ °C}, V_I = 5.0 \text{ V}$)

1. Not tested in production, specified by design

Table 6.Current limit characteristics
 $(V_1 = 5.5 V, I_0 = rated current, T_J = 25 °C, unless otherwise specified)$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
I _{OS}	Short-circuit output current	$V_I = 5 V$, OUT connected to GND, device enabled into short-circuit	0.7	1.0	1.3	A



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$(v_1 = 5.5 v, v_0 = rated current, v_1 = 25 °C, unless otherwise specified$					1)	
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
1.	Switch turned OFF	No load		1.0	5.0	μA
IOFF	Switch turned Of T	No load; -40 < T _J < 125 °C			10	μA
L.	Switch turned ON	No load		70	90	μA
ION	Switch turned ON	No load; -40 < T _J < 125 °C			100	μA
		Output grounded, switch is OFF			10	μA
I _{leakage}	Output leakage current	Output grounded, switch is OFF; -40 < T_J < 125 °C			20	μA

Table 7. Supply current characteristics

$(V_1 = 5.5 \text{ V}, I_2 = \text{rated current}, T_1 = 25 \text{ °C}, \text{ unless otherwise specified})$

Thermal characteristics Table 8.

(V_I = 5.5 V, I_O = rated current, T_J = 25 °C, unless otherwise specified)

Symbol	Parameter	Test conditions	Min	Тур	Мах	Unit
T1	Thermal shutdown threshold		135			°C
T2	Recovery from thermal shutdown		125			°C
Hyst	Hysteresis	1010		10		°C

UVLO characteristics Table 9.

$(V_1 = 5.5 \text{ V}, I_0 = \text{rated current}, T_1 = 25 \text{ °C}, \text{ unless otherwise specified})$

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Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{UVLO}	Undervoltage lockout threshold		2.0		2.5	V
Hyst	Hysteresis			100		mV

Table 10. OC pin characteristics

(V_I = 5.5 V, I_O = rated current, T_J = 25 °C, unless otherwise specified)

	Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
10	OC blanking	OCx assertion and de-assertion ⁽¹⁾		4	8	15	ms
cO'	Vo	Output low voltage				0.4	V
~105	I _{OFF}	OFF current				1.0	μA
U.	1. Not teste	d in production, specified by design.					

EN pin characteristics Table 11.

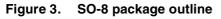
$(V_1 = 5.5 \text{ V}, I_0 = \text{rated current}, T_1 = 25 \text{ °C}, \text{ unless otherwise specified})$

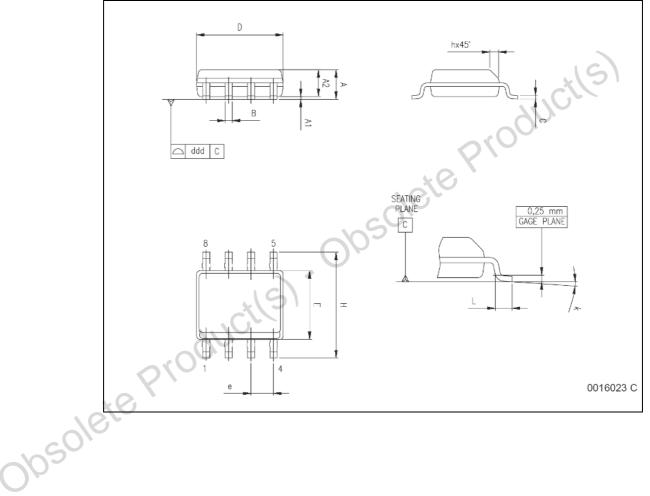
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{IH}	High level input voltage	V _I = 2.7 to 5.5 V	2.0			V
V		V _I = 4.5 to 5.5 V			0.8	V
V _{IL}	Low level input voltage	V _I = 2.7 to 4.5 V			0.4	V
I _I	Input current	$V_{IENX} = 0 \text{ or } V_{I}$	-0.5		0.5	μA



6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.







0		Millimeters		inches			
Symbol	Min	Тур	Max	Min	Тур	Max	
А	1.35		1.75	0.053		0.069	
A1	0.10		0.25	0.004		0.010	
A2	1.10		1.65	0.043		0.065	
В	0.33		0.51	0.013		0.020	
С	0.19		0.25	0.007		0.010	
D	4.80		5.00	0.189		0.197	
Е	3.80		4.00	0.15	C	0.157	
е		1.27			0.050	7	
Н	5.80		6.20	0.228	.00.	0.244	
h	0.25		0.50	0.010		0.020	
L	0.40		1.27	0.016		0.050	
k		•	8° (n	nax.)			
ddd			0.10			0.004	

Table 12. SO-8 mechanical data

7 Revision history

Table 13. Document revision history

	Date	Revision	Changes
Obsole	02-Aug-2006	1	Initial release.
	26-Feb-2008	2	Document restructured and converted to new ST template, watermark removed.
	24-Nov-2010	3	Document reformatted, added "Not Recommended for New Design" and <i>Note 1</i> below <i>Table 1</i> , corrected typo in <i>Features</i> , <i>Description</i> , <i>Section 3</i> , <i>Section 4</i> , <i>Table 3</i> , <i>Table 5</i> to <i>Table 11</i> , updated ECOPACK [®] text in <i>Section 6</i> .



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